

INCHANGE SEMICONDUCTOR

Isc N-Channel MOSFET Transistor

IRFR3607PbF

FEATURES With TO-252(DPAK) packaging · Uninterruptible power supply D(2) · High speed switching · Hard switched and high frequency circuits 100% avalanche tested G(1) Minimum Lot-to-Lot variations for robust device PIN 1.Gate performance and reliable operation 2.Drain 3.Source TO-252 package APPLICATIONS · Switching applications C 0.5 K C • ABSOLUTE MAXIMUM RATINGS(Ta=25℃) SYMBOL PARAMETER VALUE UNIT D Drain-Source Voltage 75 VDSS V V_{GSS} Gate-Source Voltage ± 20 V 50 30 Drain Current-Continuous@Tc=25°C 80 I_{D} А 56 Tc=100℃ Drain Current-Single Pulsed 310 **I**DM А G P_{D} **Total Dissipation** 140 W H H Ti **Operating Junction Temperature** -55~175 °C mm DIM MIN MAX Storage Temperature -55~175 °C Tstg 6.40 6.60 A 5.20 5.40 В C 1.15 1.35 THERMAL CHARACTERISTICS D 5.70 6.10 F 0.65

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SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	1.05	°C /W	
Rth(ch-a)	Channel-to-ambient thermal resistance	110	°C/W	

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0

0.75

0.40 0.60 0.90 1.10

2.50

2.40

10.1

2.10

2.10

9.90



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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25^{\circ}\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	75			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} =±20V; I _D =0.25mA	2		4	v
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =46A		7.34	9.0	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} =0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 75V; V _{GS} = 0V@Tc=25℃ Tc=125℃			20 250	μA
V _{SDF}	Diode forward voltage	I _{SD} =46A, V _{GS} = 0 V			1.3	v

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